# **Supporting Information**

#### A Novel 2D Carbon material T-graphene supported 3d Transition Metals as Efficient

#### **Oxygen Reduction Catalysts**

Run Jiang, Zelong Qiao, Haoxiang Xu, Dapeng Cao\*

State Key Laboratory of Organic-Inorganic Composites, Beijing University of Chemical Technology, Beijing 100029, People's Republic of China

\*Email: <u>caodp@mail.buct.edu.cn</u>

#### **1** Computation Details

#### **1.1 DFT computational methods**

All calculations were based on the first principles under the framework of spinpolarized density functional theory (DFT), using the Vienna ab initio simulation package (VASP) code<sup>1, 2</sup>, and using the Perdew-Burke-Ernzerhof (PBE) functional<sup>3-6</sup> to model the exchange correlation energy under the generalized gradient approximation (GGA). The projection enhanced wave (PAW) pseudopotential<sup>7</sup> was used to describe ionic nuclei. The plane-wave cut-off energy of 500 eV was adopted. The convergence threshold of iteration in self-consistent field (SCF) was set to  $10^{-5}$  eV per atom for energy and 0.02 eV Å<sup>-1</sup> for the force. The Gauss smearing of 0.05 eV was used for orbital occupation. Moreover, to solve the non-localization problem that the PBE exchange correlation function cannot accurately describe the electronic interaction of transition metal atoms, the DFT+U method<sup>8-</sup> <sup>12</sup> was applied through the rotation invariant method, and the value of U–J of the 3d-orbitals of 3d transition metals are set as shown in **Table S1**. A  $\Gamma$ -centered Monkhorst-Pack 3×3×1 k-point grid was used to sample the Brillouin zone for structural optimization. A large vacuum plate of 20 Å in the z direction was insert for surface isolation to prevent the interaction between two adjacent surfaces. DFT-D3 method with Becke-Jonson damping<sup>13, 14</sup> was used for vdW corrections. VASP-sol package<sup>15</sup> was used to simulate the solution environment, where the dielectric constant was set to 80. The Lobster software<sup>16</sup> was used to perform the COHP analysis<sup>17</sup>, and obtain the bonding and anti-bonding information. VASP-kit code<sup>18</sup> was used to extract electronic density of states.

#### 1.2 ORR reaction free energies

The ORR pathway on SACs were calculated in detail according to electrochemical framework developed by Nørskov and his co-workers<sup>19, 20</sup>. For each elementary step, the Gibbs reaction free energy  $\Delta G$  is defined as the difference between free energies of the initial and final states and is given by the expression:

$$\Delta G = \Delta E + \Delta Z P E - T \Delta S + \Delta G_{\rm U} + \Delta G_{\rm pH} \tag{1}$$

where  $\Delta G_U$  is the free energy change caused by the applied potential U ( $\Delta G_U = -neU$ ), and U is the applied potential vs. RHE electrode, e is the transferred elementary charge and n is the transferred proton-electron pairs.  $\Delta G_{pH}$  is the corrected value of H<sup>+</sup> free energy ( $\Delta G_{pH} =$  $-k_BT \ln[H^+] = pH \times k_BT \ln 10$ , where  $k_B$  is the Boltzmann constant and T is the temperature). According to Nernst equation,  $U_{RHE}^0 = 1.23$  V.

Therefore, the reaction free energy of  $\Delta G_1$ ,  $\Delta G_2$ ,  $\Delta G_3$ ,  $\Delta G_4$  for ORR can be calculated using the following equations:

$$\Delta G_1 = \Delta G_{*OOH} - 4.92 + \Delta G_U + \Delta G_{pH}$$
<sup>(2)</sup>

$$\Delta G_2 = \Delta G_{*O} - \Delta G_{*OOH} + \Delta G_U + \Delta G_{pH}$$
(3)

$$\Delta G_3 = \Delta G_{*OH} - \Delta G_{*O} + \Delta G_U + \Delta G_{pH}$$
<sup>(4)</sup>

$$\Delta G_4 = -\Delta G_{*OH} + \Delta G_U + \Delta G_{pH} \tag{5}$$

Since it is difficult to obtain the exact free energy of O, OH and OOH radicals in the electrolyte solution, the adsorption free energy  $\Delta G_{*O}$ ,  $\Delta G_{*OH}$ , and  $\Delta G_{*OOH}$  are relative to the free energy of stoichiometrically appropriate amounts of H<sub>2</sub>O and H<sub>2</sub>, defined as follows:

$$\Delta G_{*0} = E_{*0} + E_{H_2} - E_{H_20} - E^* + \Delta ZPE - T\Delta S$$
(6)

$$\Delta G_{*OH} = E_{*OH} + 0.5 \times E_{H_2} - E_{H_2O} - E^* + \Delta ZPE - T\Delta S$$
<sup>(7)</sup>

$$\Delta G_{*OOH} = E_{*OOH} + 1.5 \times E_{H_2} - 2 \times E_{H_2O} - E^* + \Delta ZPE - T\Delta S$$
(8)

where  $\Delta E$  is the reaction energy of reactants and product adsorbed on the catalyst surface;  $\Delta ZPE$  and  $\Delta S$  are the zero-point energy and entropy correction.<sup>1</sup> The values used for zeropoint energy corrections of intermediates are listed in **Table S2**. Energy values for H<sub>2</sub>O, O<sub>2</sub> and H<sub>2</sub> are listed in **Table S3**.

#### 1.3 bond order

The bond order is defined as half the difference between the number of bonding electrons and the number of anti-bonding electrons<sup>21</sup>:

bond order = 
$$(N_{bonding} - N_{anti-bonding}) / 2$$
 (9)

where  $N_{bonding}$  and  $N_{anti-bonding}$  represent the electrons number of bonding and anti-bonding, respectively. The higher the bond order, the stronger the orbital interaction between cations and oxygenated intermediates.

### **2** Supplementary Figures



Figure S1. The charge density diagram of graphene.



Figure S2. The carbon network of (a) graphene and (b) T-graphene.



**Figure S3**. The schematic diagram of the formation process of TM-Gra. Brown and gold balls represent carbon (C) and 3d TM respectively. Gray balls represent carbon (C) in TMC<sub>4</sub>-Gra and nitrogen (N) in TMN<sub>4</sub>-Gra configurations. Red dashed box represents the atoms replaced on the T-graphene support.



Figure S4. The illustration of dual-vacancy pore size in (a) graphene and (b) T-graphene.



**Figure S5**. The stable energy ( $E_{stable}$ ) of TMC<sub>4</sub> located on T-graphene and graphene materials *versus* the electronegativity of metal.



Figure S6. The optimized configuration of (a)  $CuC_4$ -Tgra and (b)  $ScC_4$ -Tgra adsorbing oxygen intermediates.



**Figure S7**. The relationship of (a)  $\Delta G_{*O}$  versus  $\Delta G_{*OH}$  and (b)  $\Delta G_{*OOH}$  versus  $\Delta G_{*OH}$ .



Figure S8. \*OH adsorption energy ( $\Delta G_{*OH}$ ) of all TM-Tgra and TM-Gra.



**Figure S9**. The relationship of (a)  $\Delta G_{*O}$  of TM-Tgra *versus*  $\Delta G_{*O}$  of TM-Gra and (b)  $\Delta G_{*OOH}$  of TM-Tgra *versus*  $\Delta G_{*OOH}$  of TM-Gra.



Figure S10. The free energy diagram of CuN<sub>4</sub> with weak binging strength with intermediates.



Figure S11. The d-orbital electronic arrangement of (a) Fe(II) and (b) Mn(II) with high, intermediate and low spin states.







Figure S12. PDOS and PCOHP before and after adsorbing \*OH on TM-Tgra and TM-Gra.



Figure S13. The relationship of  $\Delta G_{*OH}$  versus d-band center ( $\epsilon_d$ ).



Figure S14. The relationship between (a)  $\alpha$ -spin state and (b)  $\beta$ -spin state d-band centers of TM-Tgra and that of TM-Gra.

## **3** Supplementary Tables

Sc	Ti	V	Cr	Mn	Fe	Со	Ni	Cu	Zn
2.11	2.58	2.72	2.79	3.06	3.29	3.42	3.40	3.87	4.12

Table S1 The values of U–J parameters for DFT/PBE+U calculations.<sup>22</sup>

 Table S2 The values used for zero-point energy corrections (eV).

Species	Adsorbed on clean slab
*0	0.070
*ОН	0.330
*OOH	0.430

Table S3 Energy values for  $H_2O$ ,  $O_2$  and  $H_2$ .

	Pressure (bar)	E <sub>DFT</sub> (eV)	ZPE (eV)	G (eV)
<b>O</b> <sub>2</sub> (g)	1	_	_	-9.900
H <sub>2</sub> (g)	1	-6.773	-0.045	-6.818
H <sub>2</sub> O(l)	0.035	-14.228	-0.000	-14.228

TM	E <sub>TM</sub> (eV)	Xm <sup>23</sup>	<b>r</b> <sub>M</sub> (Å) <sup>23</sup>
Sc	-6.647	1.36	1.59
Ti	-8.458	1.54	1.48
V	-9.688	1.63	1.44
Cr	-10.017	1.66	1.30
Mn	-9.374	1.55	1.29
Fe	-8.600	1.83	1.24
Со	-7.461	1.88	1.18
Ni	-5.939	1.91	1.17
Cu	-4.319	1.90	1.22
Zn	-1.520	1.65	1.20

 Table S4 The properties of 3d-transition metals.

 Table S5 The stability energy (eV) of all TM-Tgra and TM-Gra configurations.

ТМ	TMC <sub>4</sub> -Tgra	TMN <sub>4</sub> -Tgra	TMC <sub>4</sub> -Gra	TMN <sub>4</sub> -Gra
Sc	-5.986	-6.104	-3.851	-5.030
Ti	-5.062	-3.306	-3.322	-2.594
V	-2.750	-1.174	-1.270	-0.355
Cr	-2.231	-1.198	-0.881	-0.752
Mn	-2.643	-1.175	-1.165	-0.595
Fe	-1.921	-0.078	-0.639	-0.137
Co	-1.547	0.209	-0.326	-0.037
Ni	-2.012	-0.246	-0.934	-0.610
Cu	-2.604	-0.013	-1.377	0.012
Zn	-3.771	-2.233	-2.430	-1.897

	*OH	*0	*OOH	Uonset	$\Delta G_1$	$\Delta G_2$	$\Delta G_3$	$\Delta G_4$
ScC <sub>4</sub> -Tgra	_	_	—	—	_	—	_	_
TiC <sub>4</sub> -Tgra	0.682	2.186	3.896	0.682	0.206	-0.48	-0.274	0.548
VC <sub>4</sub> -Tgra	-0.223	0.166	2.916	-0.223	-0.774	-1.52	0.841	1.453
CrC <sub>4</sub> -Tgra	-0.060	0.170	3.253	-0.060	-0.437	-1.853	1.000	1.290
MnC <sub>4</sub> -Tgra	0.489	1.357	3.532	0.489	-0.158	-0.945	0.362	0.741
FeC <sub>4</sub> -Tgra	0.839	1.716	4.020	0.839	0.330	-1.074	0.353	0.391
CoC <sub>4</sub> -Tgra	0.686	1.737	3.689	0.686	-0.001	-0.722	0.179	0.544
NiC <sub>4</sub> -Tgra	0.840	2.432	3.881	0.840	0.191	-0.219	-0.362	0.390
CuC <sub>4</sub> -Tgra	_	—	—	—	_	—	—	-
ZnC <sub>4</sub> -Tgra	1.308	3.698	4.529	0.391	0.839	0.399	-1.160	-0.078
ScN <sub>4</sub> -Tgra	0.595	2.523	3.872	0.595	0.182	-0.119	-0.698	0.635
TiN <sub>4</sub> -Tgra	0.119	0.269	3.322	0.119	-0.368	-1.823	1.080	1.111
VN <sub>4</sub> -Tgra	-0.450	-0.675	2.694	-0.450	-0.996	-2.139	1.455	1.680
CrN <sub>4</sub> -Tgra	0.229	1.431	3.458	0.229	-0.232	-0.797	0.028	1.001
MnN <sub>4</sub> -Tgra	0.679	2.539	3.928	0.679	0.238	-0.159	-0.630	0.551
FeN <sub>4</sub> -Tgra	1.048	2.186	4.046	0.874	0.356	-0.630	0.092	0.182
CoN <sub>4</sub> -Tgra	1.051	3.331	4.214	0.706	0.524	0.347	-1.050	0.179
NiN <sub>4</sub> -Tgra	1.672	2.995	4.740	0.180	1.050	-0.515	-0.093	-0.442
CuN <sub>4</sub> -Tgra	1.360	3.773	4.551	0.369	0.861	0.452	-1.183	-0.130
ZnN <sub>4</sub> -Tgra	0.323	2.915	3.701	0.323	0.011	0.444	-1.362	0.907
ScC <sub>4</sub> -Gra	0.124	0.951	3.460	0.124	-0.230	-1.279	0.403	1.106
TiC <sub>4</sub> -Gra	0.664	2.219	3.872	0.664	0.182	-0.423	-0.325	0.566
VC <sub>4</sub> -Gra	-0.349	0.129	2.960	-0.349	-0.730	-1.601	0.752	1.579
CrC <sub>4</sub> -Gra	-0.063	0.310	3.158	-0.063	-0.532	-1.618	0.857	1.293
MnC <sub>4</sub> -Gra	0.284	1.118	3.465	0.284	-0.225	-1.117	0.396	0.946
FeC <sub>4</sub> -Gra	0.774	1.677	3.991	0.774	0.301	-1.084	0.327	0.456
CoC <sub>4</sub> -Gra	0.507	1.657	3.425	0.507	-0.265	-0.538	0.08	0.723

**Table S6** Adsorption free energies of \*OH, \*O and \*OOH (eV) and ORR onset potential ( $U_{onset}$ ) (V) on TM-Tgra and TM-Gra. And reaction barriers ( $\Delta G_1 \sim \Delta G_4$ ) (eV) of ORR elementary reactions at 1.23 V on TM-Tgra and TM-Gra.

NiC <sub>4</sub> -Gra	0.734	2.484	3.732	0.734	0.042	-0.018	-0.520	0.496
CuC <sub>4</sub> -Gra	1.770	3.730	4.855	0.065	1.165	0.105	-0.730	-0.540
ZnC <sub>4</sub> -Gra	1.146	3.697	4.396	0.524	0.706	0.531	-1.321	0.084
ScN <sub>4</sub> -Gra	-0.037	1.841	3.041	-0.037	-0.649	0.030	-0.648	1.267
TiN <sub>4</sub> -Gra	-0.381	-0.506	2.839	-0.381	-0.851	-2.115	1.355	1.611
VN <sub>4</sub> -Gra	-0.980	-1.236	2.331	-0.980	-1.359	-2.337	1.486	2.210
CrN4-Gra	-0.079	0.768	3.072	-0.079	-0.618	-1.074	0.383	1.309
MnN <sub>4</sub> -Gra	0.119	1.224	3.358	0.119	-0.332	-0.904	0.125	1.111
FeN <sub>4</sub> -Gra	0.797	1.933	3.880	0.797	0.190	-0.717	0.094	0.433
CoN <sub>4</sub> -Gra	0.753	2.524	3.888	0.753	0.198	-0.134	-0.541	0.477
NiN <sub>4</sub> -Gra	1.511	3.743	4.533	0.387	0.843	0.440	-1.002	-0.281
CuN <sub>4</sub> -Gra	1.102	3.519	4.304	0.616	0.614	0.445	-1.187	0.128
ZnN <sub>4</sub> -Gra	-0.024	2.439	3.367	-0.024	-0.323	0.302	-1.233	1.254

	$\varepsilon_{d, \alpha}$ (eV)	$\epsilon_{d,\beta}$ (eV)	$\varepsilon_{\rm d}$ (eV)
ScC <sub>4</sub> -Tgra	3.861	3.948	3.905
TiC <sub>4</sub> -Tgra	2.393	2.393	2.393
VC <sub>4</sub> -Tgra	0.751	2.335	1.529
CrC <sub>4</sub> -Tgra	-0.960	2.799	0.860
MnC <sub>4</sub> -Tgra	-2.637	2.883	-0.004
FeC <sub>4</sub> -Tgra	-5.038	0.303	-2.433
CoC <sub>4</sub> -Tgra	-3.191	-0.064	-1.656
NiC <sub>4</sub> -Tgra	-0.849	-0.848	-0.848
CuC <sub>4</sub> -Tgra	-2.914	-2.913	-2.913
ZnC <sub>4</sub> -Tgra	-8.322	-8.319	-8.320
ScN <sub>4</sub> -Tgra	2.737	2.739	2.738
TiN <sub>4</sub> -Tgra	1.222	2.447	1.826
VN <sub>4</sub> -Tgra	-0.800	1.925	0.537
CrN <sub>4</sub> -Tgra	-1.162	3.596	1.057
MnN <sub>4</sub> -Tgra	-3.269	3.510	-0.044
FeN <sub>4</sub> -Tgra	-2.373	0.859	-0.781
CoN <sub>4</sub> -Tgra	-2.595	-0.955	-1.783
NiN <sub>4</sub> -Tgra	-2.422	-2.421	-2.421
CuN <sub>4</sub> -Tgra	-4.787	-3.704	-4.247
ZnN <sub>4</sub> -Tgra	-7.684	-7.682	-7.683
ScC <sub>4</sub> -Gra	3.815	3.965	3.889
TiC <sub>4</sub> -Gra	2.288	2.295	2.292
VC <sub>4</sub> -Gra	0.336	1.635	0.978
CrC <sub>4</sub> -Gra	-1.222	2.227	0.455
MnC <sub>4</sub> -Gra	-2.888	2.453	-0.317
FeC <sub>4</sub> -Gra	-5.006	0.145	-2.494
CoC <sub>4</sub> -Gra	-3.070	-0.065	-1.590
NiC <sub>4</sub> -Gra	-1.118	-1.117	-1.118
CuC <sub>4</sub> -Gra	-3.390	-3.387	-3.389
ZnC <sub>4</sub> -Gra	-8.649	-8.644	-8.647

**Table S7** The  $\alpha$ -spin ( $\epsilon_{d, \alpha}$ ),  $\beta$ -spin state ( $\epsilon_{d, \beta}$ ), and total electronic state ( $\epsilon_{d}$ ) d-band center of TM-Tgra and TM-Gra.

2.449	2.450	2.450
1.082	2.292	1.678
-1.029	1.597	0.259
-1.407	3.161	0.729
-3.522	3.154	-0.342
-2.876	0.182	-1.379
-2.877	-1.308	-2.101
-2.723	-2.722	-2.722
-5.047	-3.975	-4.512
-7.785	-7.783	-7.784
	2.449 1.082 -1.029 -1.407 -3.522 -2.876 -2.877 -2.723 -5.047 -7.785	$\begin{array}{cccccccccccccccccccccccccccccccccccc$

#### Reference

1. Kresse, G.; Furthmüller, J., Efficiency of ab-initio total energy calculations for metals and semiconductors using a plane-wave basis set. *Computational Materials Science* **1996**, *6*, 15-50.

2. Kresse, G.; Furthmüller, J., Efficient iterative schemes for ab initio total-energy calculations using a plane-wave basis set. *PHYSICAL REVIEW B* **1996**, *54* (16), 11169-11185.

3. Perdew, J. P.; Burke, K.; Ernzerhof, M., Generalized Gradient Approximation Made Simple. **1996**, *77* (18), 3865-3868.

4. Xia, D.; Yang, X.; Xie, L.; Wei, Y.; Jiang, W.; Dou, M.; Li, X.; Li, J.; Gan, L.; Kang, F., Direct Growth of Carbon Nanotubes Doped with Single Atomic Fe–N4 Active Sites and Neighboring Graphitic Nitrogen for Efficient and Stable Oxygen Reduction Electrocatalysis. *Advanced Functional Materials* **2019**, *29* (49), 1906174.

5. Chen, Y.; Gao, R.; Ji, S.; Li, H.; Tang, K.; Jiang, P.; Hu, H.; Zhang, Z.; Hao, H.; Qu, Q.; Liang, X.; Chen, W.; Dong, J.; Wang, D.; Li, Y., Atomic-Level Modulation of Electronic Density at Cobalt Single-Atom Sites Derived from Metal-Organic Frameworks: Enhanced Oxygen Reduction Performance. *Angew Chem Int Ed Engl* **2021**, *60* (6), 3212-3221.

6. Hu, X.; Chen, S.; Chen, L.; Tian, Y.; Yao, S.; Lu, Z.; Zhang, X.; Zhou, Z., What is the Real Origin of the Activity of Fe-N-C Electrocatalysts in the O(2) Reduction Reaction? Critical Roles of Coordinating Pyrrolic N and Axially Adsorbing Species. *J Am Chem Soc* **2022**, *144* (39), 18144-18152.

7. Kresse, G.; Joubert, D., From ultrasoft pseudopotentials to the projector augmentedwave method. *PHYSICAL REVIEW B* **1999**, *59* (3), 1758-1775.

8. Dudarev, S. L.; Botton, G. A.; Savrasov, S. Y.; Humphreys, C. J.; Sutton, A. P., Electron-energy-loss spectra and the structural stability of nickel oxide: An LSDA+U study. *PHYSICAL REVIEW B* **1998**, *57* (3), 1505-1509.

9. Duan, Z.; Henkelman, G., Surface Charge and Electrostatic Spin Crossover Effects in CoN4 Electrocatalysts. *ACS Catalysis* **2020**, *10* (20), 12148-12155.

10. Yin, S. H.; Yang, J.; Han, Y.; Li, G.; Wan, L. Y.; Chen, Y. H.; Chen, C.; Qu, X. M.; Jiang, Y. X.; Sun, S. G., Construction of Highly Active Metal-Containing Nanoparticles and FeCo-N(4) Composite Sites for the Acidic Oxygen Reduction Reaction. *Angew Chem Int Ed Engl* **2020**, *59* (49), 21976-21979.

11. Yao, X.; Zhu, Y.; Xia, T.; Han, Z.; Du, C.; Yang, L.; Tian, J.; Ma, X.; Hou, J.; Cao, C., Tuning Carbon Defect in Copper Single-Atom Catalysts for Efficient Oxygen Reduction. *Small* **2023**, *19* (28), e2301075.

12. Cheng, X.; Yang, J.; Yan, W.; Han, Y.; Qu, X.; Yin, S.; Chen, C.; Ji, R.;

Li, Y.; Li, G.; Li, G.; Jiang, Y.; Sun, S., Nano-geometric deformation and synergistic Co nanoparticles—Co-N4 composite sites for proton exchange membrane fuel cells. *Energy* & *Environmental Science* **2021**, *14* (11), 5958-5967.

13. Grimme, S.; Ehrlich, S.; Goerigk, L., Effect of the damping function in dispersion corrected density functional theory. *J Comput Chem* **2011**, *32* (7), 1456-65.

14. Grimme, S.; Antony, J.; Ehrlich, S.; Krieg, H., A consistent and accurate ab initio parametrization of density functional dispersion correction (DFT-D) for the 94 elements H-Pu. *J Chem Phys* **2010**, *132* (15), 154104.

15. Mathew, K.; Sundararaman, R.; Letchworth-Weaver, K.; Arias, T. A.; Hennig, R. G., Implicit solvation model for density-functional study of nanocrystal surfaces and reaction pathways. *J Chem Phys* **2014**, *140* (8), 084106.

16. Maintz, S.; Deringer, V. L.; Tchougreeff, A. L.; Dronskowski, R., LOBSTER: A tool to extract chemical bonding from plane-wave based DFT. *J Comput Chem* **2016**, *37* (11), 1030-5.

17. Deringer, V. L.; Tchougreeff, A. L.; Dronskowski, R., Crystal orbital Hamilton population (COHP) analysis as projected from plane-wave basis sets. *J Phys Chem A* **2011**, *115* (21), 5461-6.

18. Wang, V.; Xu, N.; Liu, J.-C.; Tang, G.; Geng, W.-T., VASPKIT: A user-friendly interface facilitating high-throughput computing and analysis using VASP code. *Computer Physics Communications* **2021**, *267*, 108033.

19. Nørskov, J. K.; Rossmeisl, J.; Logadottir, A.; Lindqvist, L.; Kitchin, J. R.; Bligaard, T.; Jo'nsson, H., Origin of the Overpotential for Oxygen Reduction at a Fuel-Cell Cathode. *J. Phys. Chem. B* **2004**, *108*, 17886-17892.

20. Nørskov, J. K.; Bligaard, T.; Logadottir, A.; Bahn, S.; Hansen, L. B.; Bollinger,
M.; Bengaard, H.; Hammer, B.; Sljivancanin, Z.; Mavrikakis, M.; Xu, Y.; Dahl,
S.; Jacobsen, C. J. H., Universality in Heterogeneous Catalysis. *Journal of Catalysis* 2002, 209 (2), 275-278.

21. Sun, Y.; Sun, S.; Yang, H.; Xi, S.; Gracia, J.; Xu, Z. J., Spin-Related Electron Transfer and Orbital Interactions in Oxygen Electrocatalysis. *Adv Mater* **2020**, *32* (39), e2003297.

22. Xu, H.; Cheng, D.; Cao, D.; Zeng, X. C., A universal principle for a rational design of single-atom electrocatalysts. *Nature Catalysis* **2018**, *1* (5), 339-348.

23. Haynes, W. M.; Lide, D. R.; Bruno, T. J., CRC Handbook of Chemistry and Physics. 2016.